THEODORE J. LETAVIC ET AL US 010631 HIGH FREQUENCY HIGH VOLTAGE SILICON-ON-INSULATOR DEVICE WITH MASK VARIABLE INVERSION CHANNEL AND METHOD FOR FORMING THE SAME STEVEN R. BIREN, Reg.26,531

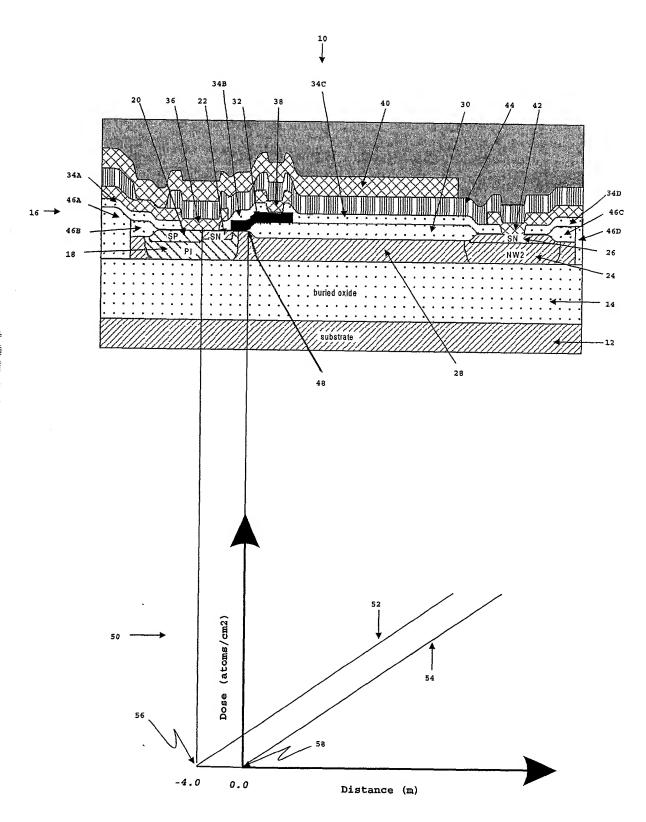


Fig. 1

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